

DESCRIPTION

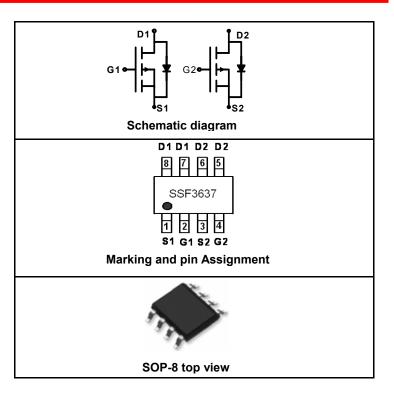
The SSF3637 uses advanced trench technology to provide excellent RDS(ON), low gate charge. It has been optimized for power management applications requiring a wide range of gave drive voltage ratings (4.5V-25V).

GENERAL FEATURES

- ullet V_{DS} = -30V,I_D = -5A R_{DS(ON)} < 87mΩ @ V_{GS}=-4.5V R_{DS(ON)} < 52mΩ @ V_{GS}=-10V
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- Battery protection
- Load switch
- Power management



PACKAGE MARKING AND ORDERING INFORMATION

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|---------|----------------|-----------|------------|------------|
| SSF3637 | SSF3637 | SOP-8 | Ø330mm | 12mm | 2500 units |

ABSOLUTE MAXIMUM RATINGS(TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|------------------|------------|------------------------|
| Drain-Source Voltage | V _{DS} | -30 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current Continuous & Current Bulgard (Note 1) | I _D | -5 | Α |
| Drain Current-Continuous@ Current-Pulsed (Note 1) | I _{DM} | -20 | Α |
| Maximum Power Dissipation | P _D | 2.0 | W |
| Operating Junction and Storage Temperature Range | T_{J}, T_{STG} | -55 To 150 | $^{\circ}\!\mathbb{C}$ |

THERMAL CHARACTERISTICS

| Thermal Resistance, Junction-to-Ambient (Note 2) | R _{θJA} | 62.5 | °C/W |
|--|------------------|------|------|
|--|------------------|------|------|

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|---------------------------------|-------------------|--|-----|-----|------|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250μA | -30 | | | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-24V,V _{GS} =0V | | | -1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | | | ±100 | nA |



| ON CHARACTERISTICS (Note 3) | | | | | | | | |
|------------------------------------|------------------------------------|--|----|------|----|----|--|--|
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =-250μA | -1 | -1.8 | -3 | V | | |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =-10V, I _D =-5A | | 39 | 52 | mΩ | | |
| | | V _{GS} =-4.5V, I _D =-4A | | 67 | 87 | | | |
| Forward Transconductance | g FS | V _{DS} =-5V, I _D =-5A | | 8 | | S | | |
| DYNAMIC CHARACTERISTICS (Note4) | | | | | | | | |
| Input Capacitance | C _{lss} | | | 700 | | PF | | |
| Output Capacitance | C _{oss} | V_{DS} =-15V, V_{GS} =0V, F=1.0MHz | | 120 | | PF | | |
| Reverse Transfer Capacitance | C _{rss} | | | 75 | | PF | | |
| SWITCHING CHARACTERISTICS (Note 4) | SWITCHING CHARACTERISTICS (Note 4) | | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | | 9 | | nS | | |
| Turn-on Rise Time | t _r | V _{DD} =-15V, I _D =-1A | | 5 | | nS | | |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =-10V, R_{GEN} =6 Ω | | 30 | | nS | | |
| Turn-Off Fall Time | t _f | | | 15 | | nS | | |
| Total Gate Charge | Qg | | | 14.7 | | nC | | |
| Gate-Source Charge | Q_{gs} | V _{DS} =-15V, I _D =-5A,V _{GS} =-10V | | 2 | | nC | | |
| Gate-Drain Charge | Q_{gd} | | | 3.8 | | nC | | |
| DRAIN-SOURCE DIODE CHARACTERISTICS | | | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =-1A | | -0.8 | -1 | V | | |

NOTES:

- Repetitive Rating: Pulse width limited by maximum junction temperature.
 Surface Mounted on FR4 Board, t ≤ 10 sec.
 Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

- 4. Guaranteed by design, not subject to production testing.



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

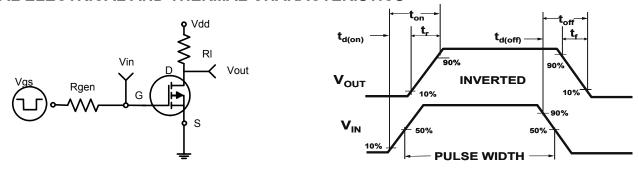
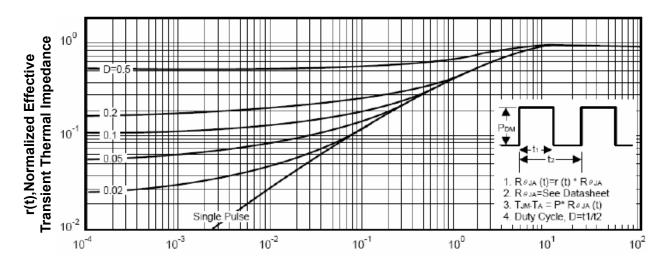


Figure1:Switching Test Circuit

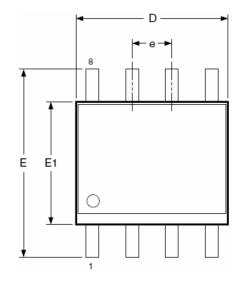
Figure 2:Switching Waveforms

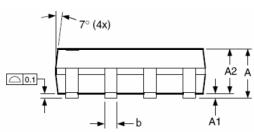


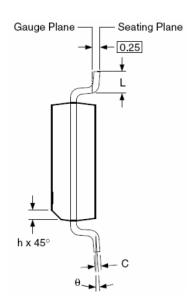
Square Wave Pluse Duration(sec)
Figure 3: Normalized Maximum Transient Thermal Impedan



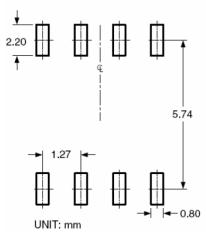
SOP-8 PACKAGE INFORMATION







RECOMMENDED LAND PATTERN



| Symbols | Min. | Nom. | Max. | | | |
|---------|----------|------|------|--|--|--|
| Α | 1.35 | 1.65 | 1.75 | | | |
| A1 | 0.10 | _ | 0.25 | | | |
| A2 | 1.25 | 1.50 | 1.65 | | | |
| b | 0.31 | _ | 0.51 | | | |
| С | 0.17 | _ | 0.25 | | | |
| D | 4.80 | 4.90 | 5.00 | | | |
| E1 | 3.80 | 3.90 | 4.00 | | | |
| е | 1.27 BSC | | | | | |
| E | 5.80 | 6.00 | 6.20 | | | |
| h | 0.25 | _ | 0.50 | | | |
| L | 0.40 | _ | 1.27 | | | |
| θ | 0° | _ | 8° | | | |

Dimensions in millimeters

| Dimensions in inches | | | | | | |
|----------------------|------------|---------|-------|--|--|--|
| Symbols | Min. | Nom. | Max. | | | |
| Α | 0.053 | 0.065 | 0.069 | | | |
| A1 | 0.004 | _ | 0.010 | | | |
| A2 | 0.049 | 0.059 | 0.065 | | | |
| b | 0.012 | _ | 0.020 | | | |
| С | 0.007 | _ | 0.010 | | | |
| D | 0.189 | 0.193 | 0.197 | | | |
| E1 | 0.150 | 0.154 | 0.157 | | | |
| е | 0 | .050 BS | С | | | |
| E | 0.228 | 0.236 | 0.244 | | | |
| h | 0.010 | _ | 0.020 | | | |
| L | 0.016 | _ | 0.050 | | | |
| θ | 0 ° | _ | 8° | | | |

NOTES:

- Dimensions are inclusive of plating
 Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 6 mils.
- 3. Dimension L is measured in gauge plane.
- 4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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